# Polarization induced renormalization of local interactions in strongly correlated electron systems

#### Jeroen van den Brink



Leibniz Institute for Solid State and Materials Research Dresden



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Microscopic screening of short-range Coulomb interactions (e.g. Hubbard U)

Resonant Inelastic X-ray Scattering (RIXS) on Li₂CuO₂ → phonon screening of CT energy





# Atomic U versus solid state U

On-site Coulomb Interaction U					
Ion	config	$U_{at}(eV)$	Solid	$U_{sol}$ (eV)	
Cu	$d^9$	16.3	CuS	7.0	
Ni	$d^8$	18.0	NiO	7.5	
			NiS	5.5	
Co	$d^7$	16.2	$\mathrm{CoS}_2$	4.2	
Fe	$d^6$	14.7	FeO	7.0	
Mn	$d^5$	20.2	MnO	7.0	
C <sub>60</sub>		3.4	C <sub>60</sub>	1.6	

Effective Coulomb interaction for $C_{60}$				
Geometry	$U^{eff}$	$V^{eff}$		
Bulk theory	1.75	0.43		
Bulk exp. [20]	$1.7 \pm 0.2$	$0.4 \pm 0.2$		
(111) Surface	2.04	0.62		
Free Layer	2.49	0.92		
Monolayer on Metal	1.00	0.00		

#### Screening of Hubbard U





# Microscopic origin polarization energy



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# **Microscopic polarization**



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# **Polarizability screening of Hubbard U**

polarization field:  $\vec{P}_i = \alpha \vec{E}_i$ 

atomic polarizability:  $\alpha$ 

pol. energy:

$$E_{pol} = \frac{1}{2} \sum_{i} \vec{E}_{i} \cdot \vec{P}_{i}$$

$$\alpha_{oxygen} \approx 2A^3$$



 $U = U_{atomic} - 2E_{pol}$ 

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but does this hold at large distances?

#### Polarizability versus dielectric screening in 3D



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polarization partially antiparallel nearest neighbor V is antiscreened

 $\alpha_{oxygen} \approx 2A^3$ 

# Screening of neighbor V on 2D cubic lattice



bond angle 90°

# Screening of neighbor V on BaFe<sub>2</sub> As<sub>2</sub> lattice



$$\alpha_{arsenic} \approx 10 A^3$$

#### angle of 73° : nearest neighbor V is overscreened

Sawatzky, Elfimov, JvdB, Zaanen EPL 86, 17006 (2009)

#### New types of charge order emerge



JvdB, Meinders, Lorenzana, Eder & Sawatzky, PRL 75, 4658 (1995)

### Screened interaction in nano systems



JvdB & Sawatzky, Electronic Properties of Novel Materials - Progress in Molecular Nanostructures, 152 (1998)

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#### Apply to 1D Hubbard model

**GAP** = U - 4 - 8 
$$\sum_{n=1}^{\infty} (-1)^n \{\sqrt{1 + n^2 U^2/4} - nU/2\}$$



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# Apply to 1D Hubbard model



# **Relation to experiment: RIXS on Li<sub>2</sub>CuO<sub>2</sub>**

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**OPEN** 

#### ARTICLE

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Electron-lattice interactions strongly renormalize the charge-transfer energy in the spin-chain cuprate  $Li_2CuO_2$ 

Steve Johnston<sup>1</sup>, Claude Monney<sup>2,3</sup>, Valentina Bisogni<sup>4,5</sup>, Ke-Jin Zhou<sup>2,6</sup>, Roberto Kraus<sup>4</sup>, Günter Behr<sup>4</sup>, Vladimir N. Strocov<sup>2</sup>, Jiři Málek<sup>7</sup>, Stefan-Ludwig Drechsler<sup>4</sup>, Jochen Geck<sup>4</sup>, Thorsten Schmitt<sup>2</sup> & Jeroen van den Brink<sup>4,8</sup>









X-ray scattering: photon in  $\rightarrow$  solid  $\rightarrow$  photon out

*inelastic:*  $\omega_{out} < \omega_{in}$ 

resonant: tune  $\omega_{in}$  to an atomic absorption edge



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scattering via absorptionemission matrix elements





# $RIXS = |GS\rangle \rightarrow XAS \rightarrow |INTERMEDIATE\rangle \rightarrow XES \rightarrow |FS\rangle$

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Local atomic transition

# $RIXS = |GS\rangle \rightarrow XAS \rightarrow |INTERMEDIATE\rangle \rightarrow XES \rightarrow |FS\rangle$ Complicated state with strong core-hole potential

Local atomic transition











**RIXS** can probe universal effective low energy behavior

#### **Resonant Scattering Intensity**

$$\begin{array}{l} \textit{RIXS} \\ \textit{amplitude} \end{array} \mathcal{F}_{fg}(\mathbf{k},\mathbf{k}',\boldsymbol{\epsilon},\boldsymbol{\epsilon}',\omega_{\mathbf{k}},\omega_{\mathbf{k}'}) = \sum_{n} \frac{\langle f | \, \mathcal{D}'^{\dagger} \, | n \rangle \, \langle n | \, \mathcal{D} \, | g \rangle}{E_{g} + \hbar \omega_{\mathbf{k}} - E_{n} + i \Gamma_{n}} \end{array}$$

Kramers-Heisenberg expression

H.A. Kramers and W. Heisenberg, Z. Phys. 31, 681 (1925)

**Resonant Scattering Intensity** 

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$$\begin{array}{l} \textit{RIXS} \\ \textit{transition} \\ \textit{operator} \end{array} \qquad \qquad \mathcal{D} = \frac{1}{im\omega_{\mathbf{k}}} \sum_{i=1}^{N} e^{i\mathbf{k}\cdot\mathbf{r}_{i}} \boldsymbol{\epsilon}\cdot\mathbf{p}_{i}, \end{array}$$

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RIXS intensity

$$I(\omega, \mathbf{k}, \mathbf{k}', \boldsymbol{\epsilon}, \boldsymbol{\epsilon}') = \sum_{f} |\mathcal{F}_{fg}(\mathbf{k}, \mathbf{k}', \boldsymbol{\epsilon}, \boldsymbol{\epsilon}', \omega_{\mathbf{k}})|^{2} \times \delta(E_{f} + \hbar\omega_{\mathbf{k}'} - E_{g} - \hbar\omega_{\mathbf{k}})$$

H.A. Kramers and W. Heisenberg, Z. Phys. 31, 681 (1925)

# **Oxygen K-edge RIXS on Li<sub>2</sub>CuO<sub>2</sub>**















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calculate instead local field induced lattice polarizations

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*dynamic screening very different for electronic and lattice polarizabilities*  RIJKSUNIVERSITEIT GRONINGEN

## The Hubbard model with orbital degeneracy and in polarizable media

Proefschrift

RIJKSUNIVERSITEIT GRONINGEN

## The Hubbard model with orbital degeneracy and in polarizable media

Proefschrift

http://www.rug.nl/research/portal/publications/ pub(5b75b5ad-8a1b-4ddb-92f9-f73ba8d52479).html

## **RIXS on Li<sub>2</sub>CuO<sub>2</sub>**



